

Confidential



Electronics for the Future

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Rohm Power solution for Horizon SoC

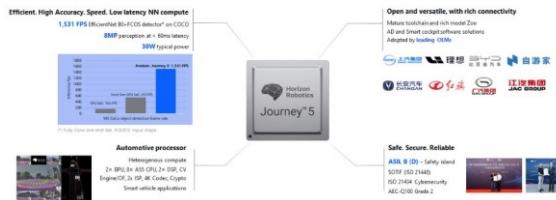
23.Feb.2023
ROHM Co., Ltd
FAE2 Div. Analog power FAE Dept.
Automotive G

Collaborate with SoC vendor to develop dedicated PMIC

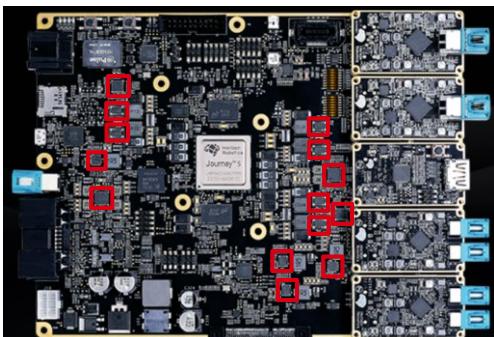
Collaborate with SoC vendor



ROHM offers flexible power supply ICs
For ADAS SoC Journey5



◆ Ref EVK



Rohm Power
Device



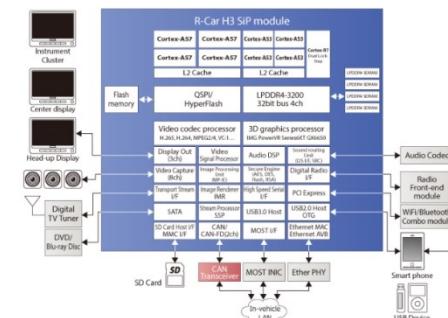
ROHM offering optimized PMICs
for Renesas R-car H3, M3, V3 and E3 SoC
series.



System Block Diagram
R-Car H3



<https://en.horizon.ai/>



Reference board of Renesas Gen.3 H3/M3
'Salvator-XS' and V3H 'Condor' are using
ROHM PMIC.

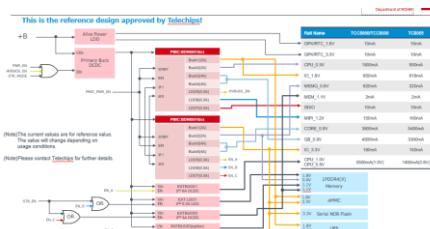


ROHM offers flexible power supply ICs
for cockpit solution /SoC Dolphin series

◆ Application



◆ Ref Block



Feature:

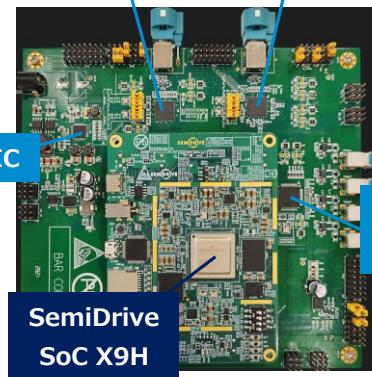
- 2 PMIC Solution
- High efficiency
- Power ON/OFF sequence



ROHM offers flexible power supply ICs
and SerDes for cockpit solution /SoC X9H

Display SerDes

Display SerDes



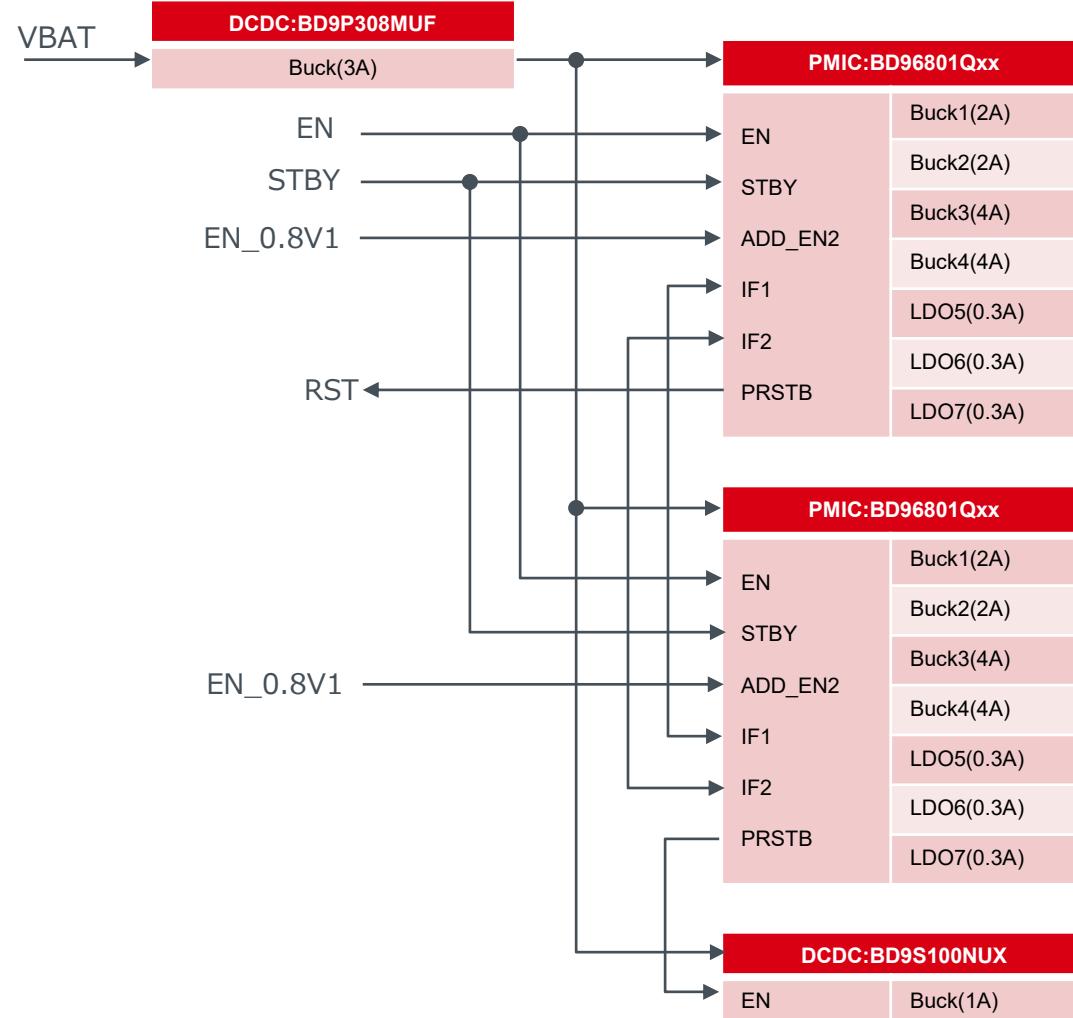
Camera
SerDes

PMIC

SemiDrive
SoC X9H

Global semiconductor supplier ROHM,
together with SemiDrive Technology,
a leading automotive-grade chip vendor
in China, have signed an advanced
technology development partnership
for the automotive field.

All power supplies are proposed in Rohm product!!



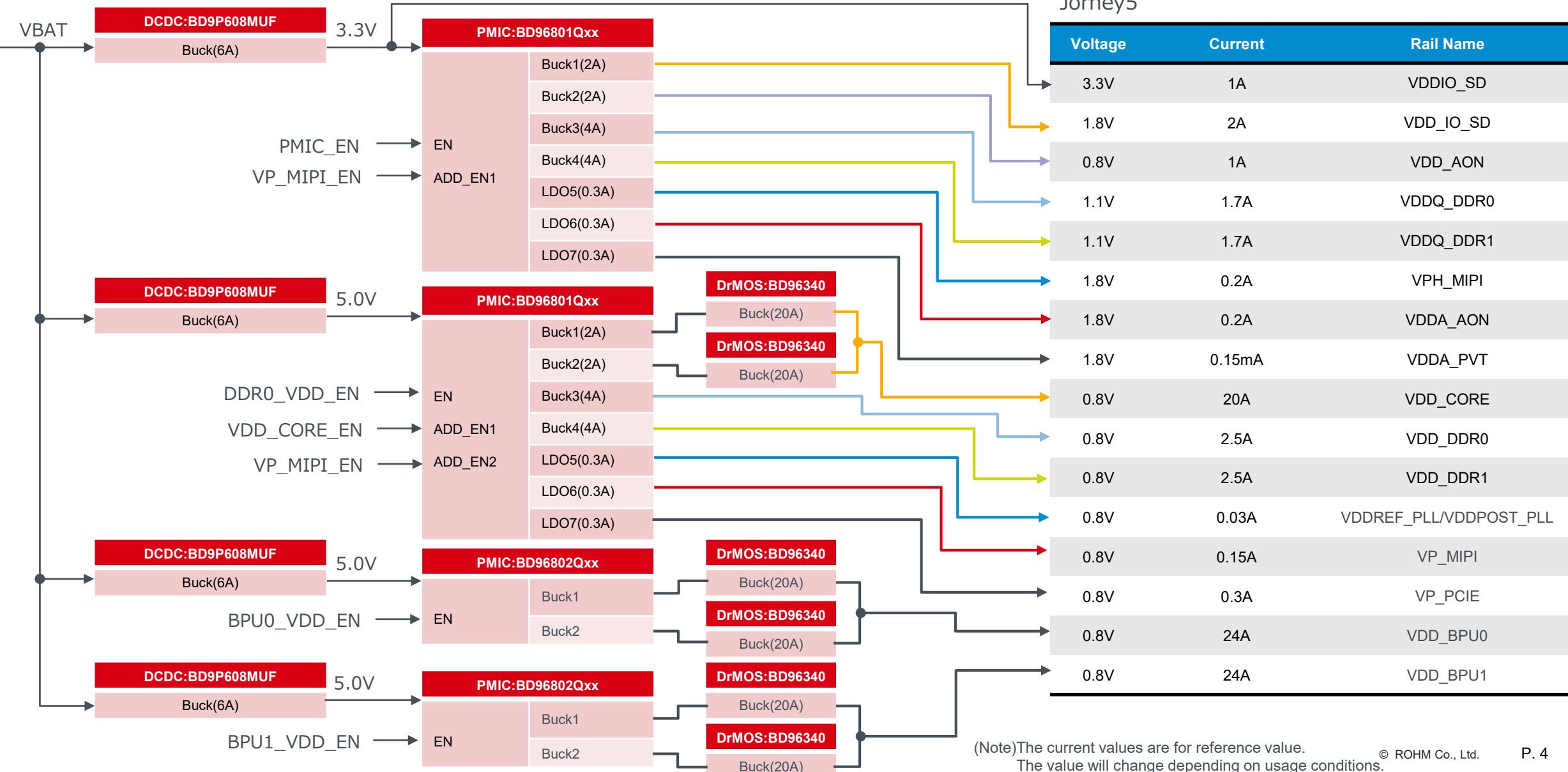
Jorney3

	Voltage	Current	Rail Name
0.8V	4.5A	VDD_CORE_PD	
0.8V	2A	VDD_CNN0	
0.8V	2A	VDD_CNN1	
0.8V	1.5A	VDD_CPU	
0.8V	0.125A	VDD_CORE_AO	
3.3V	0.01A	USB_VPH	
1.8V	0.1A	SYS_PD	
0.8V	0.28A	SYS_PD	
0.8V	2A	VDD_DDR	
1.8V	2A	SYS_IO	
3.3V	0.625	SYS_IO	
1.1V	1.45A	DDR	
1.1V	1A	LPDDR4	
1.8V	0.015A	Flash	
1.8V	0.05A	eMMC	
1.8V	0.2A	eMMC	
3.3V	0.11A	eMMC	

(Note)The current values are for reference value.

The value will change depending on usage conditions.

This is the reference design approved by Horizon!



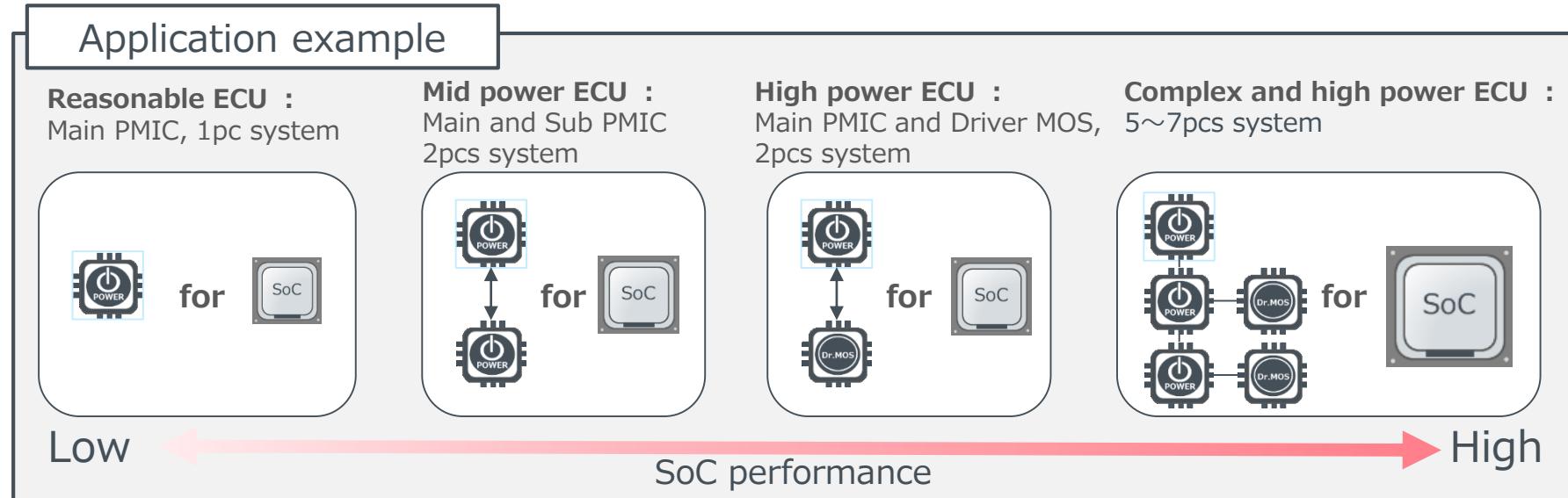
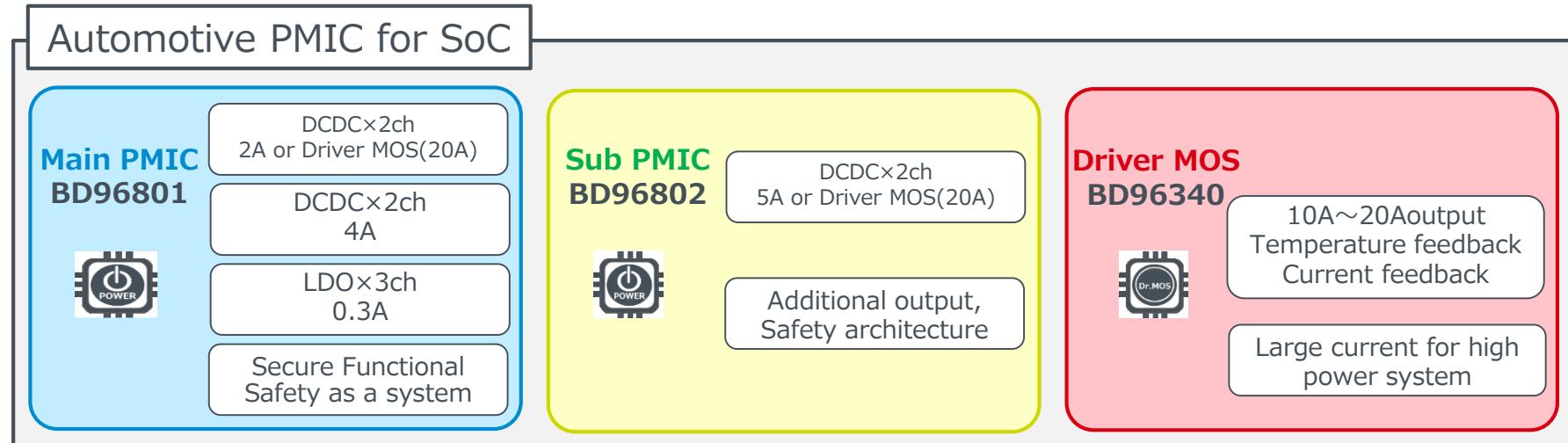
Product introduction

- ◆ SoC PMIC
- ◆ DCDC

Product introduction

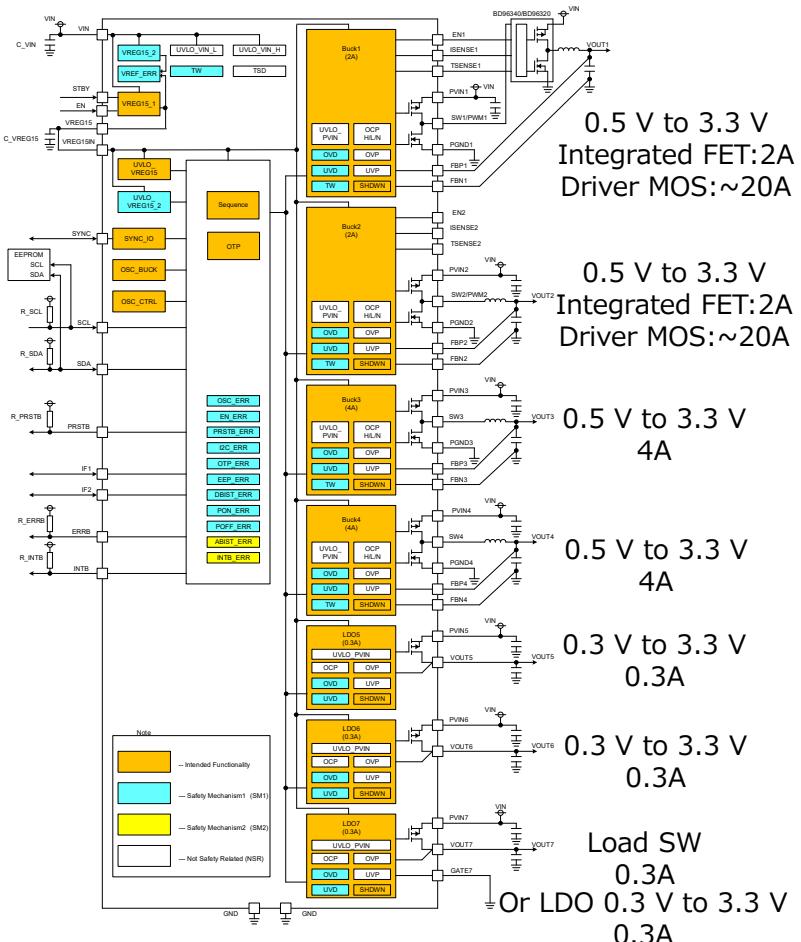
- ◆ SoC PMIC
- ◆ DCDC

Any SoC can be supported by combining the three ICs of Main PMIC, Sub PMIC, and Driver MOS.



BD96801 can be applied to various SoCs by using multi-phase and Driver MOS.
Furthermore, support a functional safety and the output voltage/sequence can be set by OTP.
Integrated Buck DCDC4ch(2A to 20A×2ch, 4A×2ch), LDO2ch, LoadSW1ch

Application Circuit



Features

- Built-in 2A MOSFETs or External Driver MOS selectable for Buck1 and Buck2.
- Built-in 4A MOSFETs for Buck3 and Buck4.
- Dual Phase Operation for Buck1&2 / Buck3&4.
- Multipurpose LDO for LDO5,6
- Load Switch or LDO selectable for LDO7 output.
- Programmable power sequencer by OTP/I2C/EEPROM
- Switching Frequency selectable (2.25/4MHz)
- Built-in protection (UVLO,OCP,OVP,UVP,TSD)
- Built-in detection (OVD,UVD, Thermal Warming)
- Built-in Q&A Watchdog, SYNC function (SYNC)
- Internal Spread Spectrum OSC
- ASIL-D support

Key specifications

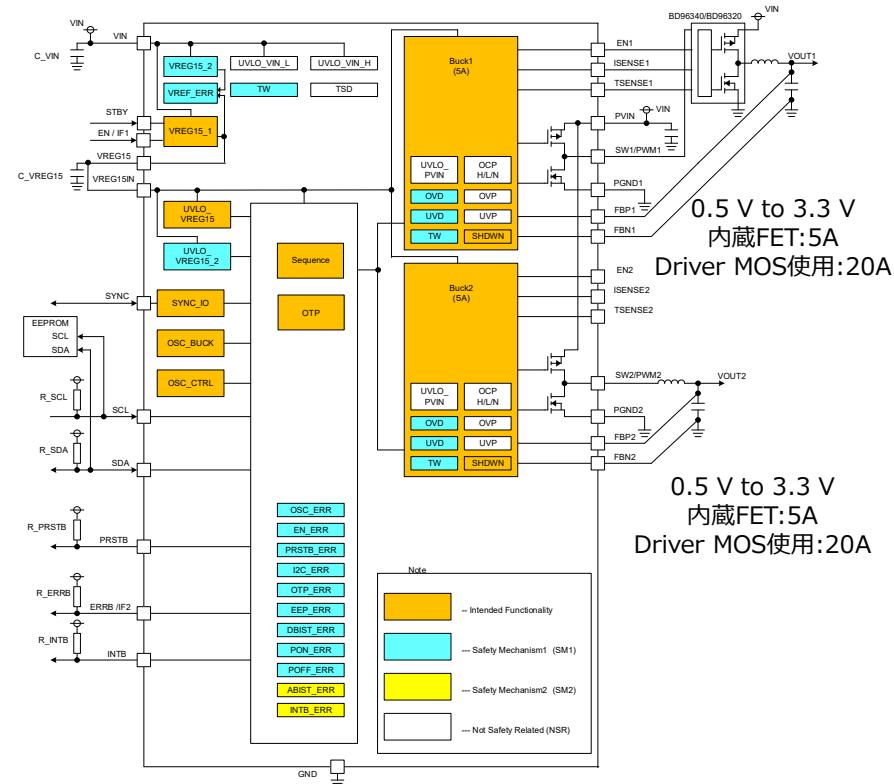
- | | |
|-------------------------------|----------------|
| ● Input voltage range | :2.7V ~ 5.5V |
| ● Operating temperature range | :-40°C ~ 125°C |
| ● Output voltage DC accuracy | :±1.2% |

Package

UQFN48FV6060 6.0mm x 6.0mm x 1.0mm

BD96802 can be applied to supply core power of various SoCs by using multi-phase and Driver MOS.
Furthermore, it can be used in combination with the Main PMIC BD96801.
Integrated Buck DCDC2ch(5A×2ch or 20A×2ch)

Application Circuit



Features

- Built-in 5A MOSFETs or External Driver MOS selectable for Buck1 and Buck2.
- Programmable power sequencer by OTP/I2C/EEPROM
- Switching Frequency selectable (2.25/4MHz)
- Built-in protection (UVLO,OCP,OVP,UVP,TSD)
- Built-in detection (OVD,UVD, Thermal Warming)
- Built-in SYNC function (SYNC)
- Internal Spread Spectrum OSC
- Sequence linkage with BD96801 is possible
- ASIL-D support

Key specifications

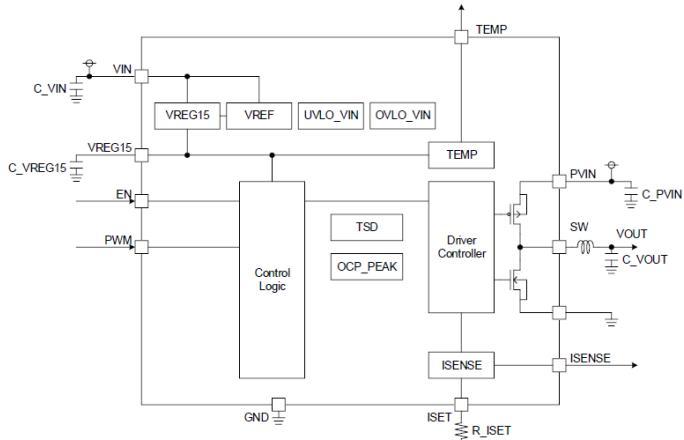
- | | |
|-------------------------------|----------------|
| ● Input voltage range | :2.7V ~ 5.5V |
| ● Operating temperature range | :-40°C ~ 125°C |
| ● Output voltage DC accuracy | ±1.2% |

Package

UQFN40FV5050 5.0mm x 5.0mm 1.0mm

**BD96340 can be used in combination with BD96801 / BD96802, which is a 1-chip MOSFET and driver.
A flip chip PKG realizes low ON resistance and can supply a large current of 20A.**

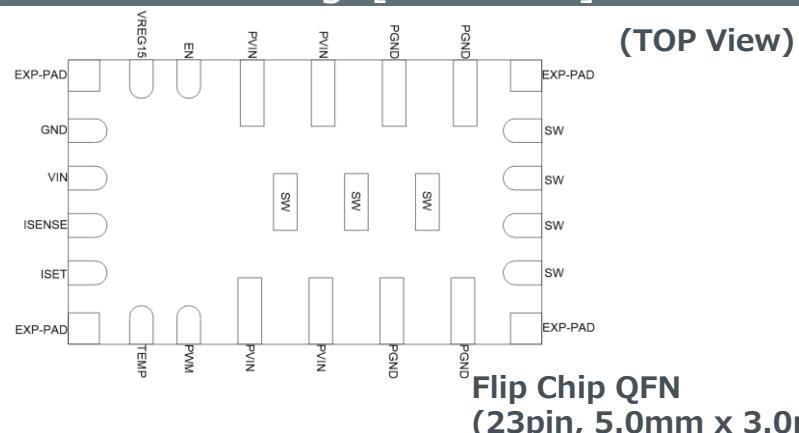
Application Circuit



Features

- AEC-Q100 Qualified
- Built-in MOSFETs of Max continuous current 20A, peak **30A** per channel.
- Built-in protection (UVLO,OVLO,OCP,TSD)
- Current Monitor Output(ISENSE)
- Die Temperature Monitor Output(TEMP)
- Automatic Phase Number Recognition Function

Package[Tentative]



Key specifications

- | | |
|-------------------------------|-------------------|
| ● Input voltage range | :2.7V ~ 5.5V |
| ● Operating temperature range | :-40°C ~ 125°C |
| ● Quiescent Current | :0uA |
| ● High Side FET On-Resistance | :4mΩ(Tentative) |
| ● Low Side FET On-Resistance | :2.5mΩ(Tentative) |

Product introduction

- ◆ SoC PMIC
- ◆ DCDC

Primary Switching Regulator N/N Line up

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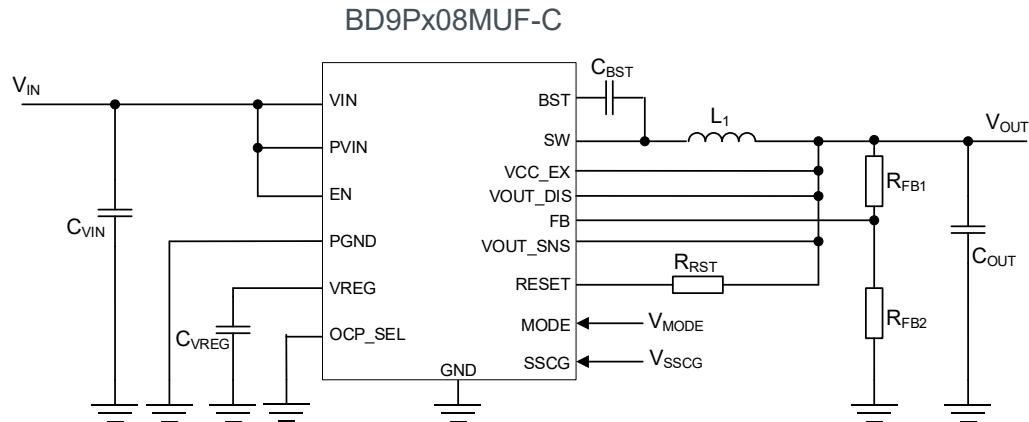
Type	Buck						
Series	BD9Pxx5xxx-C	BD9P2x6xxx-C	BD9Pxx8xxx-C	BD9Pxx9xxx-C	BD9PAxxxx-C		
Built-in FET	Nch/Nch						
VIN	3.5V to 40V	3.5V to 40V	3.5V to 40V	3.0V to 36V	3.0V to 36V		
freq	2.2MHz	440kHz	2.2MHz	2.0MHz/400kHz	2.0MHz		
Icc(typ)	10µA	10µA	10µA	5µA (T.B.D.)	50µA (T.B.D.)		
*SSCG			✓				
Vout	0.8V to 8.5V	3.3V to 5V	0.8V to 8.5V	3.3V to 5V	0.8V to 8.5V	0.8V to 9.0V	
Nano Pulse Control™				✓			
Output Current	1A	BD9P105EFV-C BD9P105MUF-C	BD9P135EFV-C BD9P155EFV-C BD9P135MUF-C BD9P155MUF-C	—	—	BD9P108MUF-C ★ BD9P109NUF-C	—
	2A	BD9P205EFV-C BD9P205MUF-C	BD9P235EFV-C BD9P255EFV-C BD9P235MUF-C BD9P255MUF-C	★ BD9P206EFV-C	★ BD9P236EFV-C ★ BD9P256EFV-C	BD9P208MUF-C ★ BD9P209NUF-C	—
	3A / 3.5A	BD9P305EFV-C (2.2MHz/440kHz Selectable)	—	—	—	BD9P308MUF-C (2.2MHz/440kHz Selectable) ★ BD9P309NUF-C (3A) ✖ BD9P409MFF-C (3.5A)	—
	6A	—	—	—	—	BD9P608MFF-C (2.2MHz/440kHz Selectable) ★ BD9P609MFF-C	—
	10A	—	—	—	—	— ★ BD9PA00EFV-C ✖ BD9PA01MFF-C	—

Features

- Nano Pulse Control™
- Integrated N-channel and N-channel power MOSFET
- Spread spectrum function
- Integrated RESET function
- External synchronization
- Built-in phase compensation
- Soft start function : 3.0ms (for 2.2MHz)
- Selectable light load mode (LLM) or Forced PWM mode
- Selectable output current (BD9P108MUF-C, BD9P208MUF-C)
- Selectable switching frequency (BD9P308MUF-C)
- OCP, SCP, TSD, OVP, UVLO
- AEC-Q100 qualified



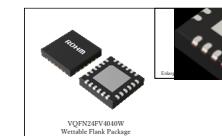
Application Circuit



* The BD9P308MUF-C has the FREQ=SEL pin instead of the OCP_SEL pin

Key Specifications

- Input voltage range : **3.5V** to 40V (Maximum rating : 42V)
Start up is over 4.0V
- Output voltage : 0.8V to 8.5V
- Output current
 - BD9P108 : 1.0A (Max)/0.5A (Max)
 - BD9P208 : 2.0A (Max)/1.5A (Max)
 - BD9P308 : 3.0A (Max)
- Switching frequency
 - BD9P108/BD9P208 : **2.2MHz**
 - BD9P308 : **2.2MHz**/440kHz
- Reference accuracy : ±1.75% (-40°C to +125°C)
±1.5% (-30°C to +105°C)
- Circuit current (No switching) : 15µA (Typ)
- Consumption current from VIN during operation : 20µA (Typ, VIN=12V, VOUT=5V, No load)
- Shut down current : 2.1µA (Typ)
- Operating temperature : -40°C to +125°C



VQFN24FV4040
4.0mm × 4.0mm × 1.0mm (Max)
Wettable Flank

Applications

- Cluster, meter panel, Car infotainment
- Automotive equipment
- Consumer power supply

Features

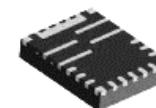
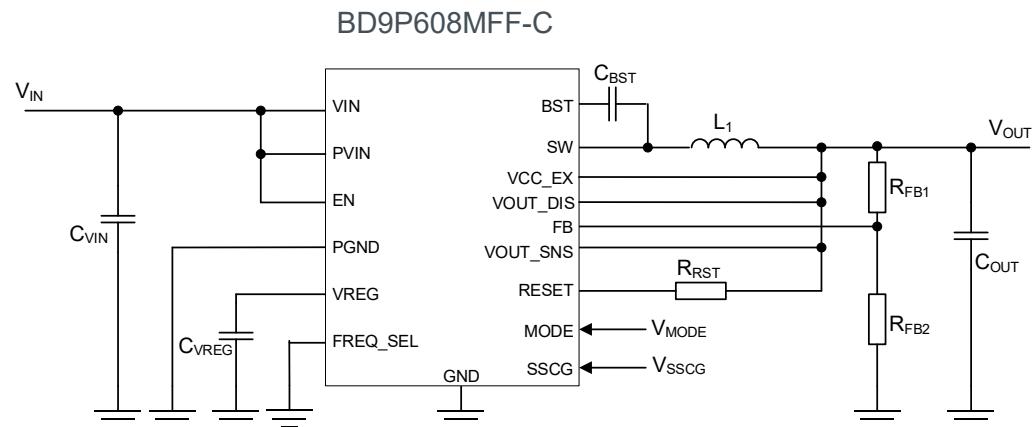
- Nano Pulse Control™
- Integrated N-channel and N-channel power MOSFET
- Spread spectrum function
- Integrated RESET function
- External synchronization
- Built-in phase compensation
- Soft start function : 3.0ms ($f = 2.2\text{MHz}$)
- Selectable light load mode (LLM) or Forced PWM mode
- Selectable switching frequency
- OCP, SCP, TSD, OVP, UVLO
- AEC-Q100 qualified



Key Specifications

- Input voltage range : 3.5V to 36V (Maximum rating : 42V)
Start up is over 4.0V
- Output current : 6.0A (Max)
- Output voltage : 0.8V to 8.5V
- Switching frequency : 2.2MHz/440kHz
- Reference : ±1.75% (-40°C to +125°C)
±1.5% (-30°C to +105°C)
- Circuit current (No switching) : 20µA (Typ)
- Consumption current from VIN during operation : 20µA (Typ, VIN=12V, VOUT=5V, No load)
- Shut down current : 2.1µA (Typ)
- Operating temperature : -40°C to +125°C

Application Circuit



FLIP CHIP PKG
VFN20FV4535
4.5mm × 3.5mm × 1.0mm (Max)
Wettable Flank

Applications

- Cluster, meter panel, Car infotainment
- Automotive equipment
- Consumer power supply

Secondary Switching Regulator Line up

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ROHM
SEMICONDUCTOR

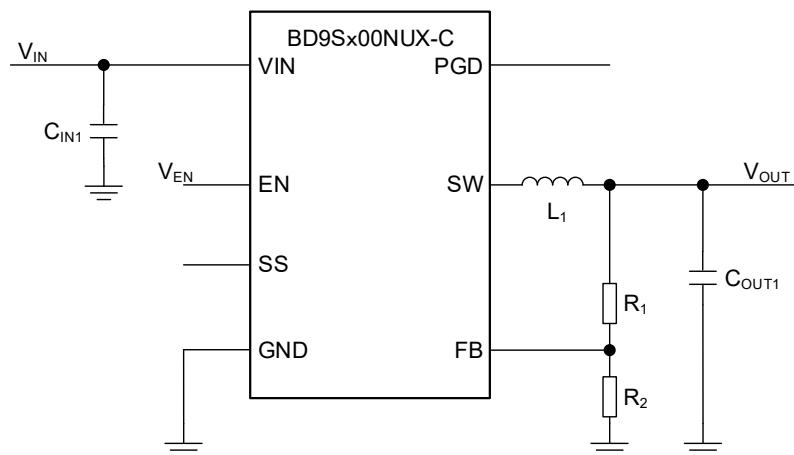
Type	Buck (1ch)					
Series	BD9Sx0xNUX-C	BD9Sx1xNUX-C	BD9Sx0xMUF-C	BD9Sx4xMFF-CZ	BD9Sx4xNUX-C	BD9SA01Fxx-C
VIN	2.7V to 5.5V					
freq	2.2MHz					
Vout	0.8V to VIN	Fixed	0.8V to VIN × 0.8V 0.6V to VIN × 0.75V (303/402)	0.5V to VIN × 0.8V	0.5V to VIN × 0.8V	0.75V to 3.3V
Package	SON 2mm × 2mm	SON 2mm × 2mm	QFN 3mm × 3mm QFN 3.5mm × 3.5mm	VFN07FV2015A 2.0mm × 1.5mm	SON 2mm × 2mm	VFN18FV3530 3.5mm x 3.0mm
Output Current	0.6A	BD9S000NUX-C	BD9S012NUX-C (1.1V) BD9SD11NUX-C (1.15V)	-	-	-
	1A	BD9S100NUX-C BD9S109NUX-C	BD9S110NUX-C (1.2V) BD9S111NUX-C (1.8V)	-	-	✗ BD9S14xNUX-C
	2A	BD9S201NUX-C BD9S209NUX-C BD9S231NUX-C	-	BD9S200MUF-C	✗ BD9S24xMFF-CZ	✗ BD9S24xNUX-C
	3A	-	-	BD9S300MUF-C ★ BD9S303MUF-C	✗ BD9S34xMFF-CZ	✗ BD9S34xNUX-C
	4A	-	-	BD9S400MUF-C BD9S402MUF-C	✗ BD9S44xMFF-CZ	-
	6A	-	-	-	✗ BD9S64xMFF-CZ	-
	12A	-	-	-	-	★ BD9SA01Fxx-C

No mark...Available in the market ★...In development ✗...In Planning

Features

- Integrated P-channel and N-channel power MOSFET
- Efficiency Optimized for 100mA to 300mA(over 80%)
- Forced PWM mode
- Available in a Small VSON package (2mm x 2mm)
- Space Saving
- Integrated Power Good function
- Built-in phase compensation
- Adjustable soft start function
- Output discharge function
(the discharge resistances and pin configuration are different between BD9S100NUX-C and BD9S109NUX-C)
- OCP, SCP, TSD, OVP, UVLO
- AEC-Q100 qualified

Application Circuit



Key Specifications

- | | |
|-------------------------|--------------------------------------|
| ● Input voltage range | : 2.7V to 5.5V (Maximum rating : 7V) |
| ● Output voltage range | : 0.8V to VIN |
| ● Reference voltage | : 0.8V ±1.5% |
| ● Output current | |
| BD9S000NUX-C | : 0.6A (Max) |
| BD9S100NUX-C | : 1.0A (Max) |
| BD9S109NUX-C | : 1.0A (Max) |
| ● Switching frequency | : 2.2MHz ±10% |
| ● Pch FET ON resistance | |
| BD9S000NUX-C | : 270mΩ (Typ) |
| BD9S100NUX-C | : 270mΩ (Typ) |
| BD9S109NUX-C | : 150mΩ (Typ) |
| ● Nch FET ON resistance | |
| BD9S000NUX-C | : 180mΩ (Typ) |
| BD9S100NUX-C | : 180mΩ (Typ) |
| BD9S109NUX-C | : 95mΩ (Typ) |
| ● Operating temperature | : -40°C to +125°C |



VSON008X2020
2.0mm × 2.0mm × 0.6mm (Max)

Applications

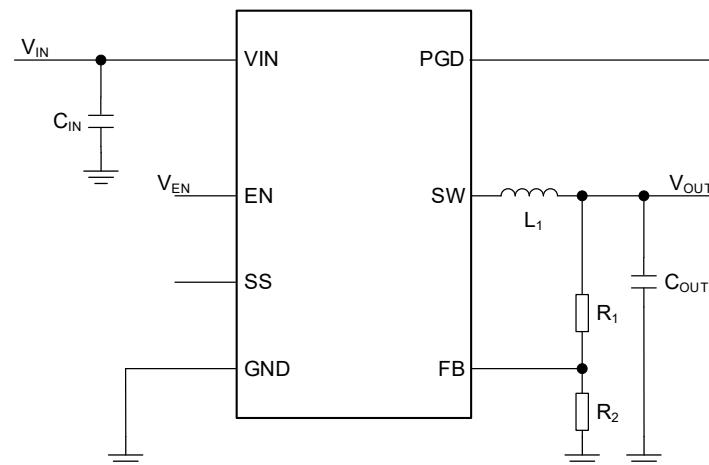
- Cluster, meter panel, Car infotainment
- Automotive equipment
- Consumer power supply

Features

- Integrated P-channel and N-channel power MOSFET
- Efficiency Optimized for 500mA to 1000mA (over 80%)
- Forced PWM mode
- Available in a Small VSON package (2mm x 2mm)
- Space Saving
- Integrated Power Good function
- Built-in phase compensation
- Adjustable soft start function
- Output discharge function
(the discharge resistances and pin configuration are different between BD9S201NUX-C and BD9S209NUX-C)
- OCP, SCP, TSD, OVP, UVLO
- AEC-Q100 qualified

Application Circuit

BD9S201NUX-C



Key Specifications

- | | |
|-------------------------|--------------------------------------|
| ● Input voltage range | : 2.7V to 5.5V (Maximum rating : 7V) |
| ● Output voltage range | : 0.8V to VIN |
| ● Reference voltage | : 0.8V ±1.5% |
| ● Output current | : 2.0A (Max) |
| ● Switching frequency | : 2.2MHz ±10% |
| ● Pch FET ON resistance | : 150mΩ (Typ) |
| ● Nch FET ON resistance | : 95mΩ (Typ) |
| ● Operating temperature | : -40°C to +125°C |



VSON08X2020
2.0mm × 2.0mm × 0.6mm (Max)

Applications

- Cluster, meter panel, Car infotainment
- Automotive equipment
- Consumer power supply

Features

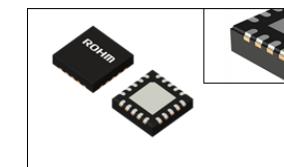
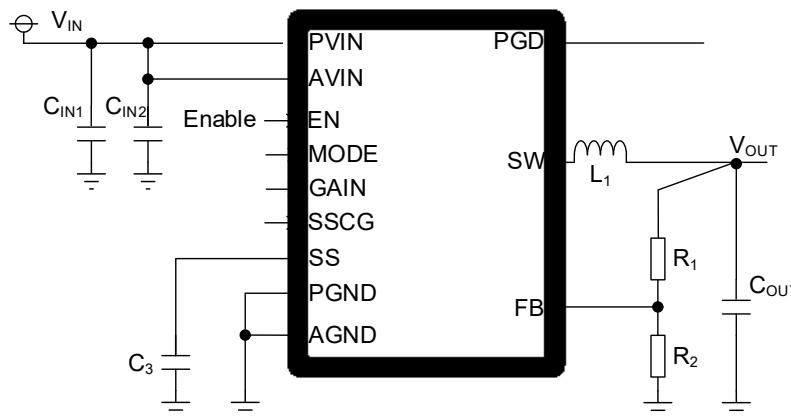
- Nano Pulse Control™
- QuiCur™
- Improvement for load transient response can achieve less COUT
- Quick load transient response can be achieved on the condition of GAIN=Hi
- Spread spectrum function
- Built-in phase compensation
- Selectable Light load mode(LLM) or Force PWM mode
- Integrated Power Good function
- Adjustable soft start function
- OCP, SCP, TSD, OVP, UVLO
- AEC-Q100 Planned to be supported



Key Specifications

- Input voltage range : 2.7V to 5.5V (Maximum rating : 7V)
- Output voltage range : 0.6V to VIN x 0.75V
- Reference voltage : 0.6V ±1.5%
- Output current : 3.0A (Max)
- Switching frequency : 2.2MHz ±10%
- Circuit current (No switching) : 22µA (Typ)
- Consumption current from VIN during operation : 44µA (Typ, VIN=5V, VOUT=1.2V, No load)
- Pch FET ON resistance Nch FET ON resistance : 65mΩ (Typ) : 43mΩ (Typ)
- Operating temperature : -40°C to +125°C

Application Circuit



VQFN20FV3535
3.5mm × 3.5mm × 1.0mm (Max)
Wettable Flank

Applications

- Cluster, meter panel, Car infotainment
- Automotive equipment
- Consumer power supply

*Designing/planning, spec, schedule etc. could change depending on the market trend.



Electronics for the Future